## NSN 5961-01-245-6246

**Fiig:** A110a0

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-245-6246 **Inclosure Material:** Metal **Overall Length:** 0.300 inches **Terminal Length:** 0.980 inches **Overall Diameter:** 0.450 inches **Function For Which Designed:** Rectifier **Electrode Internally-electrically Connected To Case:** Cathode **Mounting Method: Terminal Features Provided:** Hermetically sealed case and burn in **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 40.0 repetitive peak reverse voltage and 40.0 working peak reverse voltage and 40.0 reverse voltage, instantaneous and 48.0 nonrepetitive peak reverse voltage **Current Rating Per Characteristic:** 15.00 amperes forward current, average absolute **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No